

General Purpose Transistor Array One Differentially Connected Pair and Three Isolated Transistor Arrays

The MC3346 is designed for general purpose, low power applications for consumer and industrial designs.

Symbol

VCEO

VCBO

VEB

VCIO

IC

PD

ΤA

T_{stg}

Value

15

20

5.0

20

50

1.2

10

-40 to +85

-65 to +150

Unit

Vdc

Vdc

Vdc

Vdc

mAdc

W

mW/°C

°C

°C

• Guaranteed Base–Emitter Voltage Matching

MAXIMUM RATINGS

Collector-Emitter Voltage

Collector-Substrate Voltage

Collector Current - Continuous

Operating Temperature Range

Storage Temperature Range

Total Power Dissipation @ T_A = 25°C

Collector-Base Voltage

Emitter-Base Voltage

Derate above 25°C

Rating

- Operating Current Range Specified: 10 μA to 10 mA
- Five General Purpose Transistors in One Package



GENERAL PURPOSE TRANSISTOR ARRAY

SEMICONDUCTOR TECHNICAL DATA



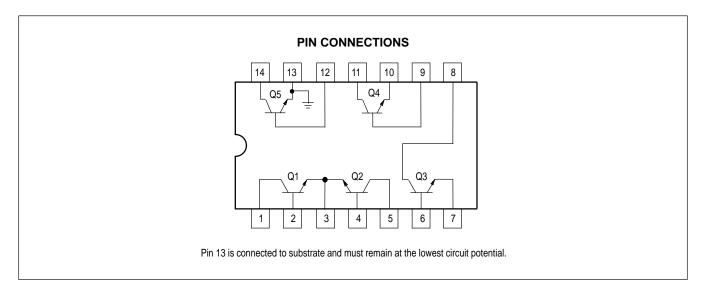
PLASTIC PACKAGE CASE 646



D SUFFIX PLASTIC PACKAGE CASE 751A (SO-14)

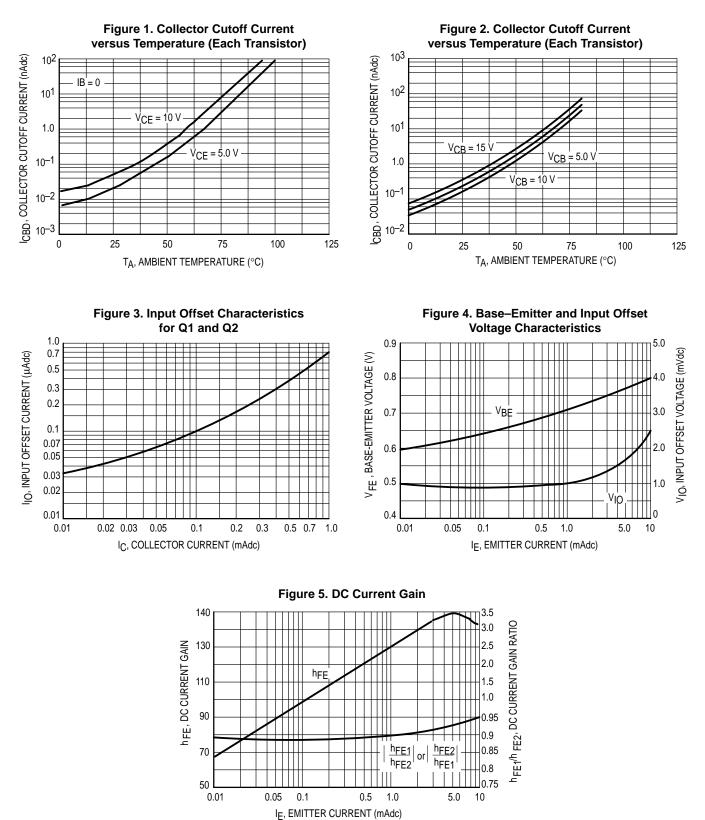
ORDERING INFORMATION

Device	Operating Temperature Range	Package	
MC3346D	$T_{\Delta} = -40^{\circ} \text{ to } +85^{\circ}\text{C}$	SO-14	
MC3356P	IA = = 40 10 403 C	Plastic DIP	



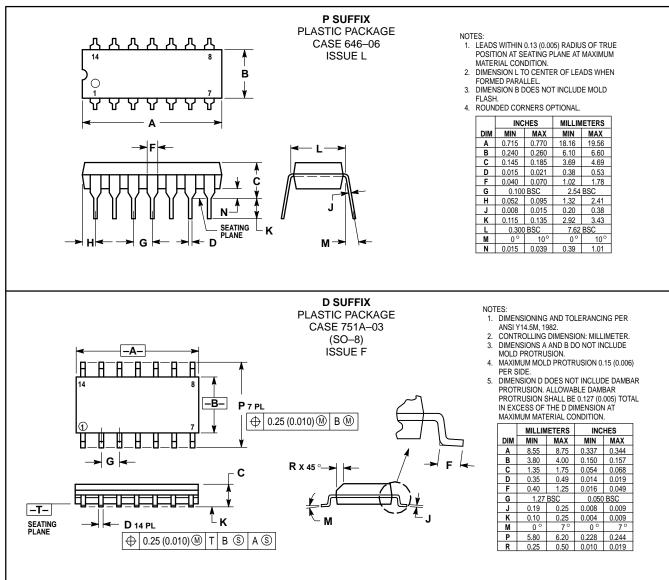
MC3346

Characteristics	Symbol	Min	Тур	Max	Unit
STATIC CHARACTERISTICS					
Collector–Base Breakdown Voltage $(I_{C} = 10 \ \mu Adc)$	V(BR)CBO	20	60	-	Vdc
Collector–Emitter Breakdown Voltage $(I_{C} = 1.0 \text{ mAdc})$	V(BR)CEO	15	-	-	Vdc
Collector–Substrate Breakdown Voltage $(I_C = 10 \ \mu A)$	V(BR)CIO	20	60	-	Vdc
Emitter–Base Breakdown Voltage (IE = 10 μ Adc)	V(BR)EBO	5.0	7.0	-	Vdc
Collector–Base Cutoff Current ($V_{CB} = 10 V_{dc}, I_E = 0$)	ІСВО	-	-	40	nAdc
DC Current Gain (I _C = 10 mAdc, V _{CE} = 3.0 Vdc) (I _C = 1.0 mAdc, V _{CE} = 3.0 Vdc) (I _C = 10 μ Adc, V _{CE} = 3.0 Vdc)	hFE	- 40 -	140 130 60		-
Base-Emitter Voltage (V _{CE} = 3.0 Vdc, I _E = 1.0 mAdc) (V _{CE} = 3.0 Vdc, I _E = 10 mAdc)	VBE	_	0.72 0.8		Vdc
Input Offset Current for Matched Pair Q1 and Q2 (V _{CE} = 3.0 Vdc, I _C = 1.0 mAdc)	I _{IO1} – I _{IO2}	-	0.3	2.0	μAdc
Magnitude of Input Offset Voltage (V _{CE} = 3.0 Vdc, I _C = 1.0 mAdc)	-	-	0.5	5.0	mVdc
Temperature Coefficient of Base–Emitter Voltage ($V_{CE} = 3.0 \text{ Vdc}, I_{C} = 1.0 \text{ mAdc}$)	ΔV _{BE} D _T	-	-1.9	-	mV/°C
Temperature Coefficient	$\frac{ \Delta V_{IO} }{D_T}$	_	1.0	_	μV/°C
Collector–Emitter Cutoff Current (V _{CE} = 10 Vdc, I _B = 0)	ICEO	-	-	0.5	μAdc
DYNAMIC CHARACTERISTICS			•		•
Low Frequency Noise Figure (V _{CE} = 3.0 Vdc, I _C = 100 μ Adc, R _S = 1.0 kΩ, f = 1.0 kHz)	NF	-	3.25	-	dB
Forward Current Transfer Ratio (V _{CE} = 3.0 Vdc, I _C = 1.0 mAdc, f = 1.0 kHz)	hFE	-	110	-	-
Short Circuit Input Impedance (V _{CE} = 3.0 Vdc, I _C = 1.0 mAdc)	h _{ie}	_	3.5	_	kΩ
Open Circuit Output Impedance (V _{CE} = 3.0 Vdc, I _C = 1.0 mAdc)	h _{oe}	-	15.6	-	μmhos
Reverse Voltage Transfer Ratio ($V_{CE} = 3.0 \text{ Vdc}, I_{C} = 1.0 \text{ mAdc}$)	h _{re}	-	1.8	-	x10 ⁻⁴
Forward Transfer Admittance (V _{CE} = 3.0 Vdc, I _C = 1.0 mAdc, f = 1.0 MHz)	Уfe	-	31–j1.5	-	-
Input Admittance (V _{CE} = 3.0 Vdc, I _C = 1.0 mAdc, f = 1.0 MHz)	Уіе	_	0.3 + j0.04	_	_
Output Admittance (V_{CE} = 3.0 Vdc, I _C = 1.0 mAdc, f = 1.0 MHz)	Уое	-	0.001 + j0.03	_	_
Current–Gain – Bandwidth Product (V _{CE} = 3.0 Vdc, I _C = 3.0 mAdc)	fT	300	550	-	MHz
Emitter-Base Capacitance ($V_{EB} = 3.0 \text{ Vdc}, I_E = 0$)	C _{eb}	-	0.6	_	pF
Collector–Base Capacitance $(V_{CB} = 3.0 \text{ Vdc}, I_{C} = 0)$	C _{cb}	_	0.58	_	pF
Collector–Substrate Capacitance ($V_{CS} = 3.0 \text{ Vdc}, I_{C} = 0$)	C _{CI}	-	2.8	-	pF



MC3346

OUTLINE DIMENSIONS



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How to reach us:

USA/EUROPE/Locations Not Listed: Motorola Literature Distribution; P.O. Box 20912; Phoenix, Arizona 85036. 1–800–441–2447 or 602–303–5454

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MFAX: RMFAX0@email.sps.mot.com - TOUCHTONE 602-244-6609 INTERNET: http://Design-NET.com JAPAN: Nippon Motorola Ltd.; Tatsumi–SPD–JLDC, 6F Seibu–Butsuryu–Center, 3–14–2 Tatsumi Koto–Ku, Tokyo 135, Japan. 03–81–3521–8315

ASIA/PACIFIC: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park, 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852–26629298

MC3346/D

